







SN54HC151, SN74HC151 SCLS110F - DECEMBER 1982 - REVISED FEBRUARY 2022

# SNx4HC151 8-Line To 1-Line Data Selectors/Multiplexers

### 1 Features

- Wide operating voltage range of 2 V to 6 V
- Outputs can drive up to 10 LSTTL loads
- Low power consumption, 80-µA max I<sub>CC</sub>
- Typical  $t_{pd}$  = 13 ns
- ±6-mA Output drive at 5 V
- Low input current of 1 µA max
- 8-Line to 1-line multiplexers can perform as:
  - Boolean-function generators
  - Parallel-to-serial converters
  - Data source selectors

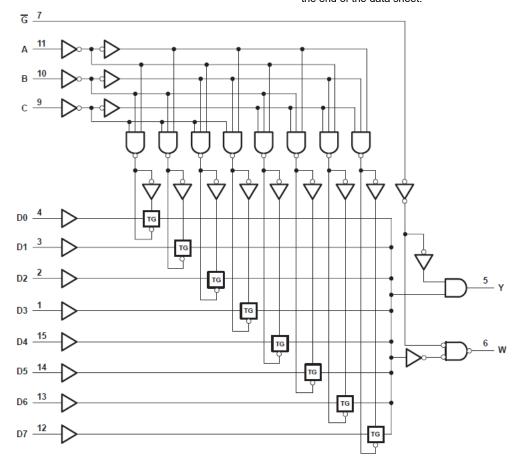
## 2 Description

This data selector/multiplexer provides full binary decoding to select one of eight data sources. The strobe (G) input must be at a low logic level to enable the inputs. A high level at the strobe terminal forces the standard output (Y) low and the inverted output (W) high.

### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
SN54HC151J	CDIP (16)	24.38 mm × 6.92 mm
SN74HC151D	SOIC (16)	9.90 mm × 3.90 mm
SN74HC151N	PDIP (16)	19.31 mm × 6.35 mm
SN74HC151NS	SO (16)	6.20 mm × 5.30 mm
SN74HC151PW	TSSOP (16)	5.00 mm × 4.40 mm
SNJ54HC151FK	LCCC (20)	8.89 mm × 8.45 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Pin numbers shown are for the D, J, N, NS, PW, and W packages.

### **Functional Block Diagram**



## **Table of Contents**

1 Features	1	7.1 Overview	8
2 Description	1	7.2 Functional Block Diagram	8
3 Revision History	2	7.3 Device Functional Modes	<u>g</u>
4 Pin Configuration and Functions	3	8 Power Supply Recommendations	10
5 Specifications	4	9 Layout	10
5.1 Absolute Maximum Ratings		9.1 Layout Guidelines	10
5.2 Recommended Operating Conditions <sup>(1)</sup>	4	10 Device and Documentation Support	
5.3 Thermal Information	4	10.1 Receiving Notification of Documentation Update	s 11
5.4 Electrical Characteristics	5	10.2 Support Resources	<mark>11</mark>
5.5 Switching Characteristics	5	10.3 Trademarks	11
5.6 Switching Characteristics	6	10.4 Electrostatic Discharge Caution	11
5.7 Operating Characteristics	6	10.5 Glossary	
6 Parameter Measurement Information		11 Mechanical, Packaging, and Orderable	
7 Detailed Description		Information	<mark>1</mark> 1

# **3 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

## Changes from Revision E (September 2003) to Revision F (February 2022)

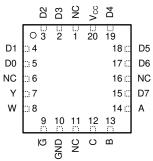
Page



# **4 Pin Configuration and Functions**

D3	1 ()	16	_ Vcc
D2	2	15	D4
D1	3	14	D5
D0	4	13	D6
Y	5	12	<u></u> □ D7
W	6	11	<u></u> Д А
G□	7	10	<del></del> □ В
GND□□□	8	9	Ш С
			1

J, D, N, NS, or PW Package 16-Pin CDIP, SOIC, PDIP, SO, TSSOP Top View



FK Package 20-Pin LCCC Top View



# **5 Specifications**

## **5.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

		<u> </u>	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	mA
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub>		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±35	mA
	Continuous current through V <sub>CC</sub> o	r GND		±70	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Section 5.2 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 5.2 Recommended Operating Conditions<sup>(1)</sup>

			SN	54HC151		SN	SN74HC151			
			MIN	NOM	MAX	MIN NOM		MAX	UNIT	
V <sub>CC</sub>	Supply voltage		2	5	6	2	5	6	V	
		V <sub>CC</sub> = 2 V	1.5			1.5			V	
V <sub>IH</sub>	V <sub>IH</sub> High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15				
		V <sub>CC</sub> = 6 V	4.2			4.2				
	V <sub>IL</sub> Low-level input voltage	V <sub>CC</sub> = 2 V			0.5			0.5	V	
V <sub>IL</sub>		V <sub>CC</sub> = 4.5 V	,		1.35			1.35		
		V <sub>CC</sub> = 6 V			1.8			1.8		
VI	Input voltage	•	0		V <sub>CC</sub>	0		V <sub>CC</sub>	V	
Vo	Output voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V	
		V <sub>CC</sub> = 2 V			1000			1000		
t <sub>t</sub>	t Input transition rise/fall time	V <sub>CC</sub> = 4.5 V	,		500			500	ns	
		V <sub>CC</sub> = 6 V			400			400		
T <sub>A</sub>	Operating free-air temperatur	e	-55		125	-40		85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## 5.3 Thermal Information

		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL MET	RIC	16 PINS	16 PINS	16 PINS	16 PINS	UNIT
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(1)</sup>	73	67	64	108	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

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<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



### **5.4 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST	V <sub>CC</sub> (V)	Т	A = 25°C		SN54HC	151	SN74HC	151	UNIT
PARAMETER	CONDITIONS <sup>(1)</sup>	ACC (A)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII
		2	1.9	1.998		1.9		1.9		
$V_{OH}$	I <sub>OH</sub> = −20 mA	4.5	4.4	4.499		4.4		4.4		
		6	5.9	5.999		5.9		5.9		V
	I <sub>OH</sub> = −6 mA	4.5	3.98	4.3		3.7		3.84		
	$I_{OH} = -7.8 \text{ mA}$	6	5.48	5.8		5.2		5.34		
	I <sub>OL</sub> = 20 μA	2		0.002	0.1		0.1		0.1	
		4.5		0.001	0.1		0.1		0.1	
V <sub>OL</sub>		6		0.001	0.1		0.1		0.1	V
	I <sub>OL</sub> = 6 mA	4.5		0.17	0.26		0.4		0.33	
	I <sub>OL</sub> = 7.8 mA	6		0.15	0.26		0.4		0.33	
I <sub>I</sub>	$V_I = V_{CC}$ or 0	6		±0.1	±100	-	±1000		±1000	nA
I <sub>CC</sub>	I <sub>O</sub> = 0	6			8	-	160		80	μA
C <sub>i</sub>		2 to 6		3	10		10		10	pF

<sup>(1)</sup>  $V_I = V_{IH} \text{ or } V_{IL}$ 

# **5.5 Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	V <sub>CC</sub> (V)	T <sub>A</sub> =	25°C		SN54HC151	SN74HC151	UNIT																				
PARAMETER	(INPUT)	(OUTPUT)	VCC (V)	MIN	TYP	MAX	MIN MA	MIN MAX	UNII																				
			2		94	250	36	312																					
	A, B, or C	Y or W	4.5		30	50	7	63																					
			6		25	43	6	54																					
		2		74	195	28	244																						
t <sub>pd</sub>	Any D	Y or W	4.5		23	39	5	49	ns																				
			6		20	33	4	41																					
			2		49	127	18	159																					
	G	Y or W	4.5		15	25	3	32																					
							1 51 11				- 5	. 5	0.00	1 01 11	101 01	101 01		1 01 11	1 01 11	101 00	1011		6		13	22	3	28	
t <sub>t</sub>		2		22	75	11	95																						
		Y or W	4.5		9	15	2	19	ns																				
			6		8	13	1	16																					



# **5.6 Switching Characteristics**

over recommended operating free-air temperature range,  $C_L$  = 150 pF (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	V AA	T	λ = 25°C		SN54HC1	51	SN74HC	151	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2		107	350		525		440	
	A, B, or C	Y or W	4.5		33	70		105		88	
			6		30	59		89		76	
			2		90	275		415		345	
$t_{pd}$	Any D	Y or W	4.5		29	51		83		69	ns
			6		25	47		72		59	
			2		67	205		310		255	
	G	Y or W	4.5		21	41		62		51	
			6		18	35		53		43	
t <sub>t</sub>			2		51	210		315		265	
		Y or W	4.5		16	42		63		53	ns
			6		14	36		53		45	

# **5.7 Operating Characteristics**

T<sub>A</sub> = 25°C

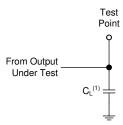
	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	No load	70	pF

### **6 Parameter Measurement Information**

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_t$  < 6 ns.

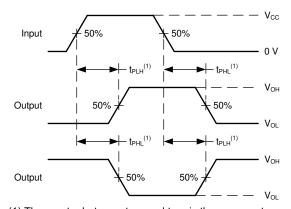
For clock inputs,  $f_{\text{max}}$  is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



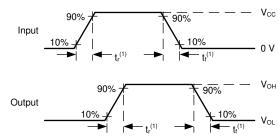
(1) C<sub>L</sub> includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for Push-Pull Outputs



(1) The greater between t<sub>PLH</sub> and t<sub>PHL</sub> is the same as t<sub>pd</sub>.

Figure 6-2. Voltage Waveforms, Propagation **Delays for Standard CMOS Inputs** 



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

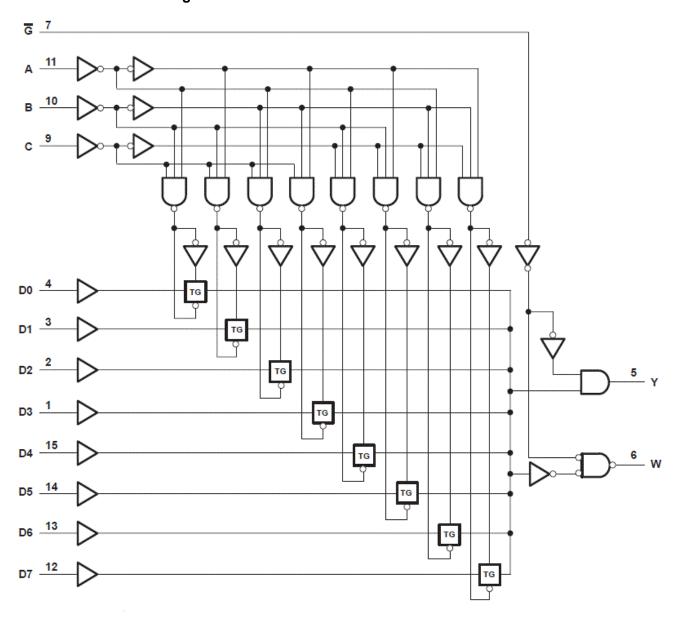
Figure 6-3. Voltage Waveforms, Input and Output **Transition Times for Standard CMOS Inputs** 

# 7 Detailed Description

## 7.1 Overview

This data selector/multiplexer provides full binary decoding to select one of eight data sources. The strobe  $(\overline{G})$  input must be at a low logic level to enable the inputs. A high level at the strobe terminal forces the standard output (Y) low and the inverted output (W) high.

## 7.2 Functional Block Diagram



Pin numbers shown are for the D, J, N, NS, PW, and W packages.



## 7.3 Device Functional Modes

Table 7-1. Function Table<sup>(1)</sup>

	INP	UTS		OUTPUTS			
	SELECT		STROBE G	Υ	w		
С	В	Α	STROBE G	•	VV		
Х	X	Х	Н	L	Н		
L	L	L	L	D0	<del>D</del> 0		
L	L	Н	L	D1	D1		
L	Н	L	L	D2	D2		
L	Н	Н	L	D3	D3		
Н	L	L	L	D4	D4		
Н	L	Н	L	D5	<u>D5</u>		
Н	Н	L	L	D6	<del>D</del> 6		
Н	Н	Н	L	D7	D7		

<sup>(1)</sup> D0, D1  $\dots$  D7 = the level of the respective D input.

# 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 9 Layout

### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.



# 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

## 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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# **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
84128012A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84128012A SNJ54HC 151FK
8412801EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8412801EA SNJ54HC151J
SN54HC151J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC151J
SN54HC151J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC151J
SN74HC151D	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HC151
SN74HC151DR	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151DR.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151DR1G4	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151DR1G4.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151DRG4	Active	Production	null (null)	2500   LARGE T&R	-	Call TI	Call TI	-40 to 85	
SN74HC151DT	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HC151
SN74HC151N	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC151N
SN74HC151N.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC151N
SN74HC151NSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151NSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151PW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-40 to 85	HC151
SN74HC151PWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151PWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC151
SN74HC151PWT	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-40 to 85	HC151
SNJ54HC151FK	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84128012A SNJ54HC 151FK
SNJ54HC151FK.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84128012A SNJ54HC 151FK
SNJ54HC151J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8412801EA SNJ54HC151J

PACKAGE OPTION ADDENDUM

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Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SNJ54HC151J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8412801EA SNJ54HC151J

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN54HC151, SN74HC151:

Catalog: SN74HC151

Automotive: SN74HC151-Q1, SN74HC151-Q1

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

# PACKAGE OPTION ADDENDUM

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Military : SN54HC151

NOTE: Qualified Version Definitions:

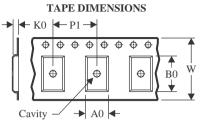
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC151DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC151DR1G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC151NSR	SOP	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC151PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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### \*All dimensions are nominal

7 till dillitoriolorio di o riorriiridi							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC151DR	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC151DR1G4	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC151NSR	SOP	NS	16	2000	353.0	353.0	32.0
SN74HC151PWR	TSSOP	PW	16	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



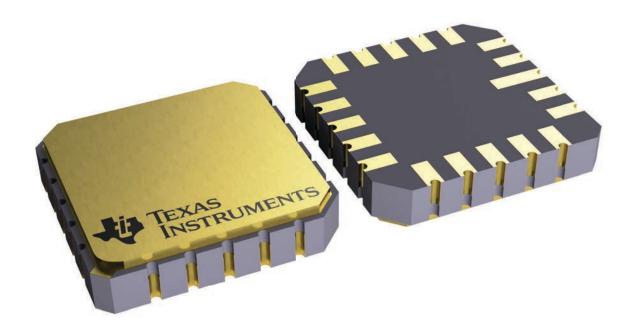
\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
84128012A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74HC151N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC151N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC151N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC151N.A	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC151FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC151FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

### 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



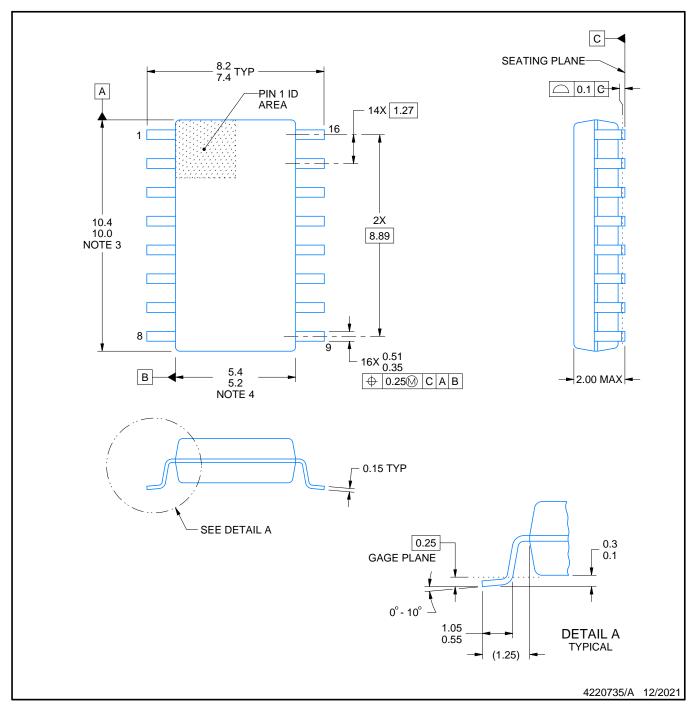
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



### NOTES:

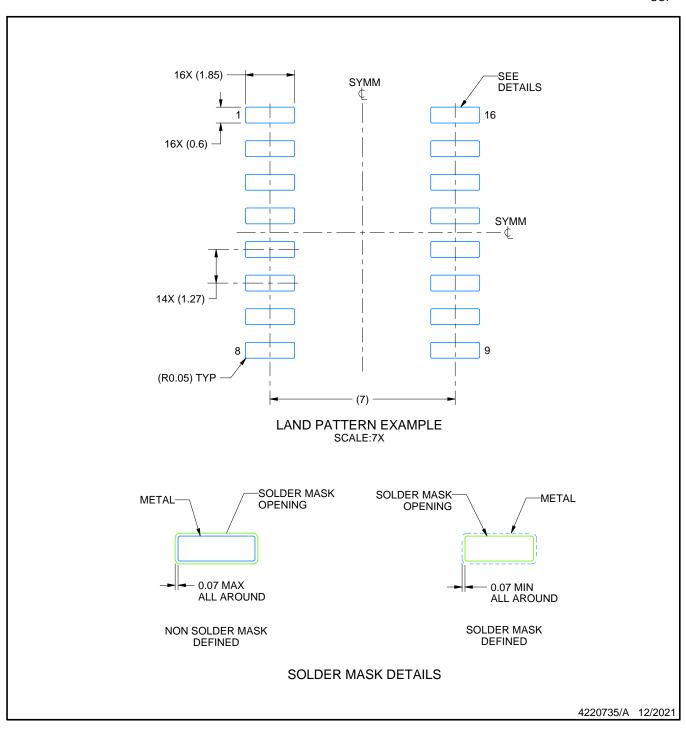
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF

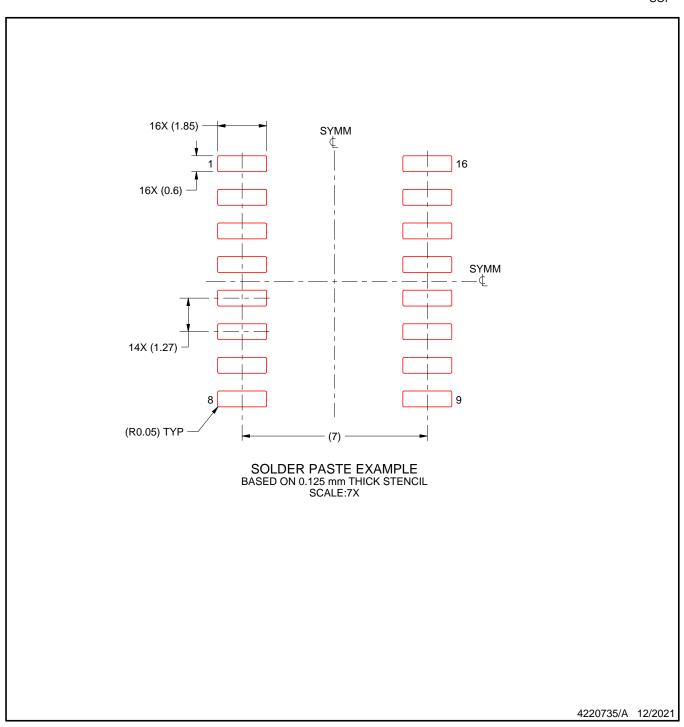


## NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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